

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|-------------------------------|--|
| 20V | 29mΩ @ V _{GS} = 10V | 6.5A |
| | 35mΩ @ V _{GS} = 4.5V | 5.2A |

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

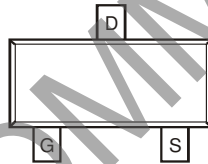
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)

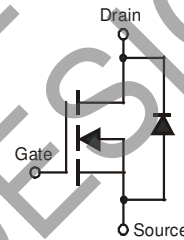
SOT23



Top View



Top View



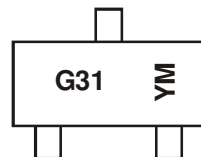
Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Qualification | Case | Packaging |
|-------------|---------------|-------|------------------|
| DMG3420U-7 | Standard | SOT23 | 3000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - 4.. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



G31 = Product Type Marking Code
 YM or YM = Date Code Marking
 Y or Y = Year (ex: G = 2019)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2009 | ~ | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 |
|------|------|---|------|------|------|------|------|------|------|------|------|
| Code | W | ~ | G | H | I | J | K | L | M | N | O |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|-----------------------------------|--------------|---------------------------|-----------|----------|------|
| Drain-Source Voltage | | | V_{DSS} | 20 | V |
| Gate-Source Voltage | | | V_{GSS} | ± 12 | V |
| Continuous Drain Current (Note 5) | Steady State | $T_A = +25^\circ\text{C}$ | I_D | 5.47 | A |
| | | $T_A = +85^\circ\text{C}$ | | 3.43 | |
| Pulsed Drain Current (Note 6) | | | I_{DM} | 20 | A |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------------|--------------------|
| Power Dissipation (Note 5) | P_D | 0.74 | W |
| Thermal Resistance, Junction to Ambient @ $T_A = +25^\circ\text{C}$ (Note 5) | $R_{\theta JA}$ | 167 | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|--------------|-----|-------|-----------|---------------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | 20 | — | — | V | $V_{GS} = 0V, I_D = 250\mu\text{A}$ |
| Zero Gate Voltage Drain Current $T_J = +25^\circ\text{C}$ | I_{DSS} | — | — | 1.0 | μA | $V_{DS} = 20V, V_{GS} = 0V$ |
| Gate-Source Leakage | I_{GSS} | — | — | ± 100 | nA | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | 0.5 | 0.95 | 1.2 | V | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ |
| Static Drain-Source On-Resistance | $R_{DS(ON)}$ | — | 21 | 29 | m Ω | $V_{GS} = 10V, I_D = 6A$ |
| | | | 25 | 35 | | $V_{GS} = 4.5V, I_D = 5A$ |
| | | | 34 | 48 | | $V_{GS} = 2.5V, I_D = 4A$ |
| | | | 65 | 91 | | $V_{GS} = 1.8V, I_D = 2A$ |
| Forward Transfer Admittance | $ Y_{fs} $ | — | 9 | — | s | $V_{DS} = 5V, I_D = 3.8A$ |
| Diode Forward Voltage | V_{SD} | — | 0.75 | 1.0 | V | $V_{GS} = 0V, I_S = 1A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C_{iss} | — | 434.7 | — | pF | $V_{DS} = 10V, V_{GS} = 0V,$ $f = 1.0\text{MHz}$ |
| Output Capacitance | C_{oss} | — | 69.1 | — | pF | |
| Reverse Transfer Capacitance | C_{riss} | — | 61.2 | — | pF | |
| Gate Resistance | R_g | — | 1.53 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1\text{MHz}$ |
| Total Gate Charge | Q_g | — | 5.4 | — | nC | $V_{GS} = 4.5V, V_{DS} = 10V,$ $I_D = 6A$ |
| Gate-Source Charge | Q_{gs} | — | 0.9 | — | nC | |
| Gate-Drain Charge | Q_{gd} | — | 1.5 | — | nC | |
| Turn-On Delay Time | $t_{D(ON)}$ | — | 6.5 | — | ns | $V_{DD} = 10V, V_{GS} = 5V,$ $R_L = 1.7\Omega, R_g = 6\Omega$ |
| Turn-On Rise Time | t_R | — | 8.3 | — | ns | |
| Turn-Off Delay Time | $t_{D(OFF)}$ | — | 21.6 | — | ns | |
| Turn-Off Fall Time | t_F | — | 5.3 | — | ns | |

- Notes:
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 6. Repetitive rating, pulse width limited by junction temperature.
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to production testing.

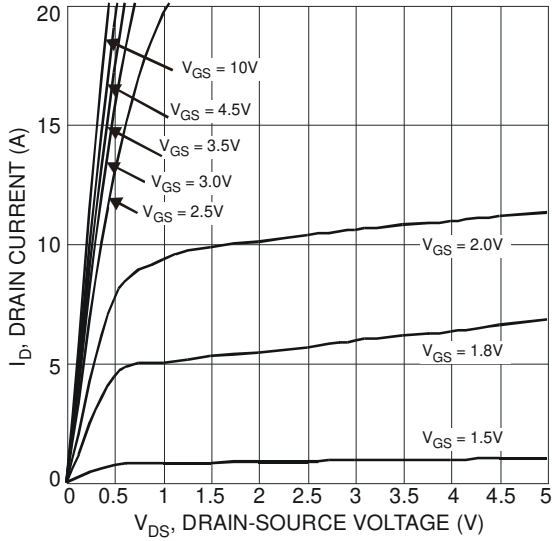


Fig. 1 Typical Output Characteristics

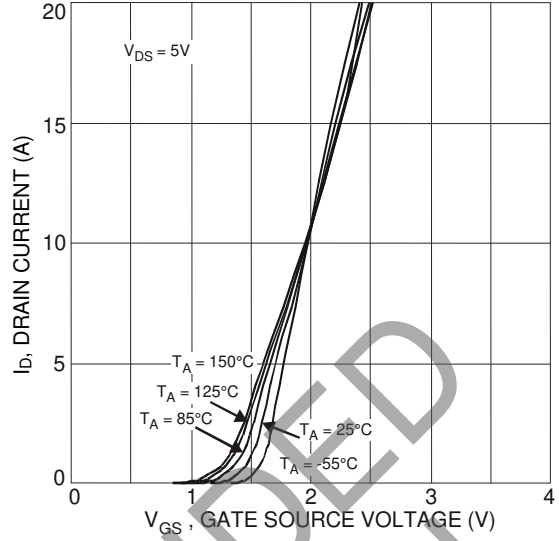


Fig. 2 Typical Transfer Characteristics

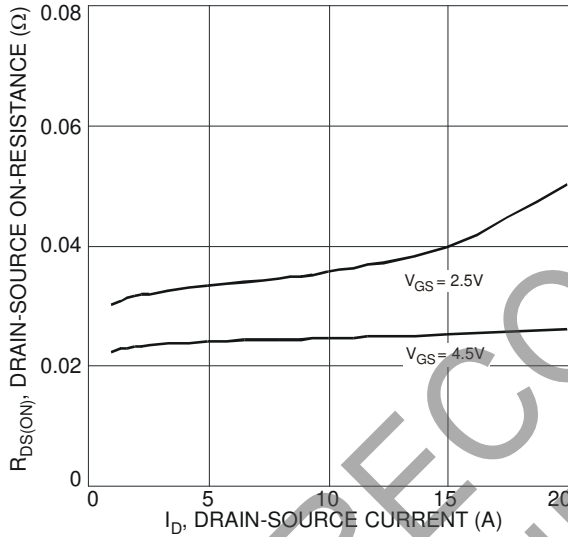


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

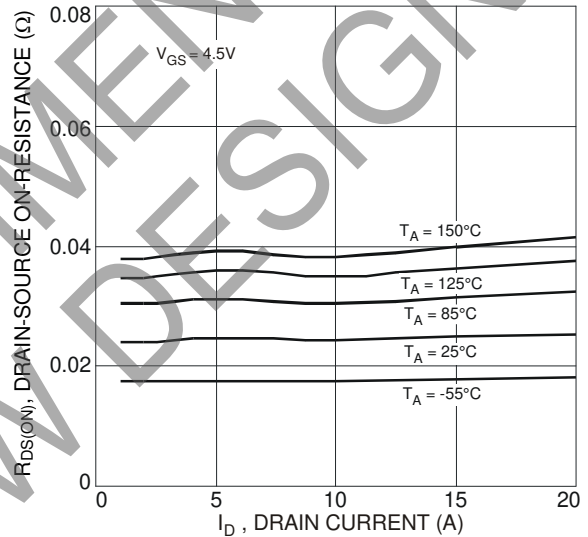


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

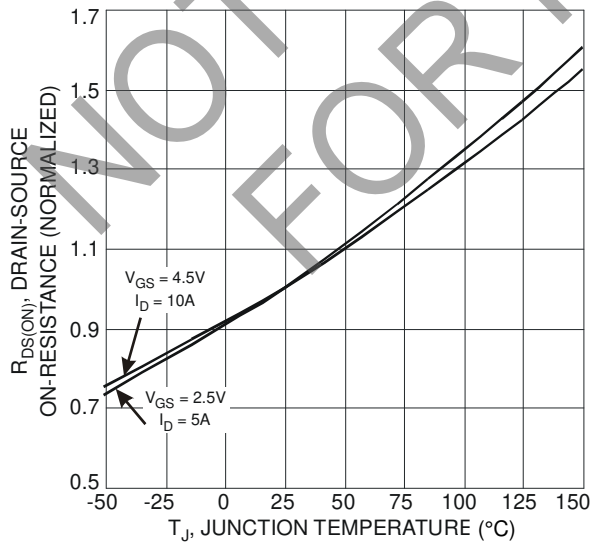


Fig. 5 On-Resistance Variation with Temperature

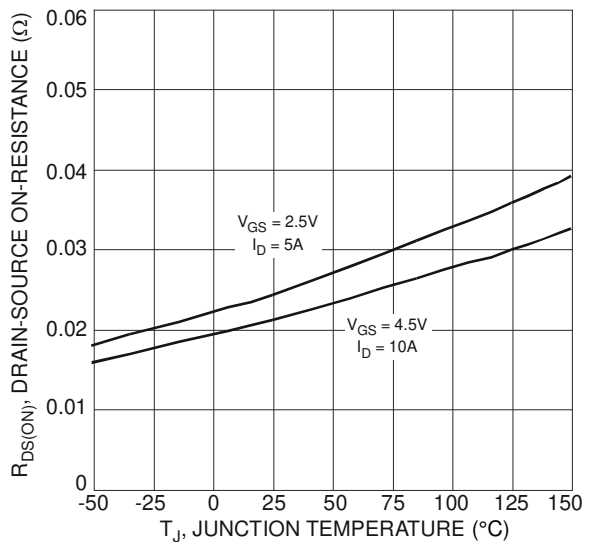


Fig. 6 On-Resistance Variation with Temperature

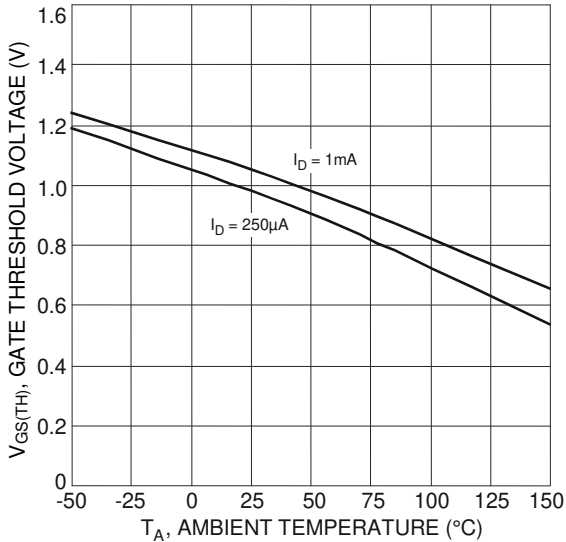


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

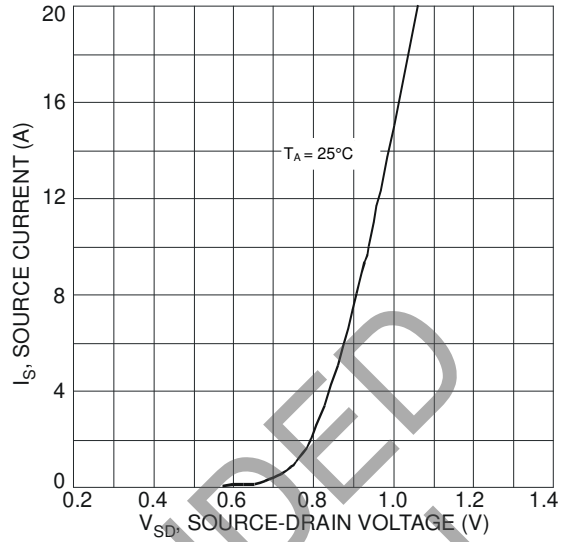


Fig. 8 Diode Forward Voltage vs. Current

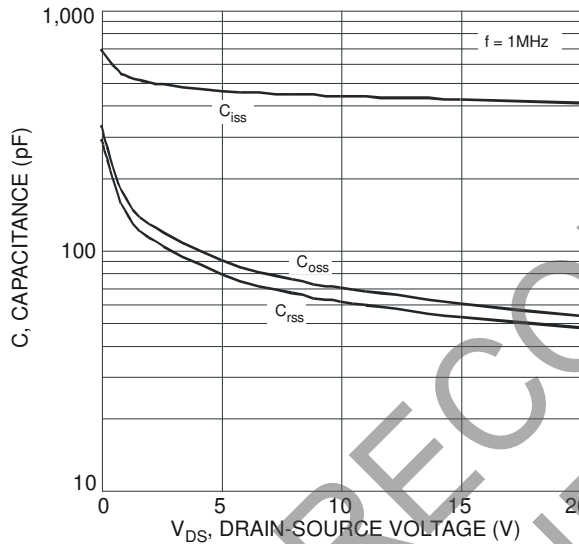


Fig. 9 Typical Capacitance

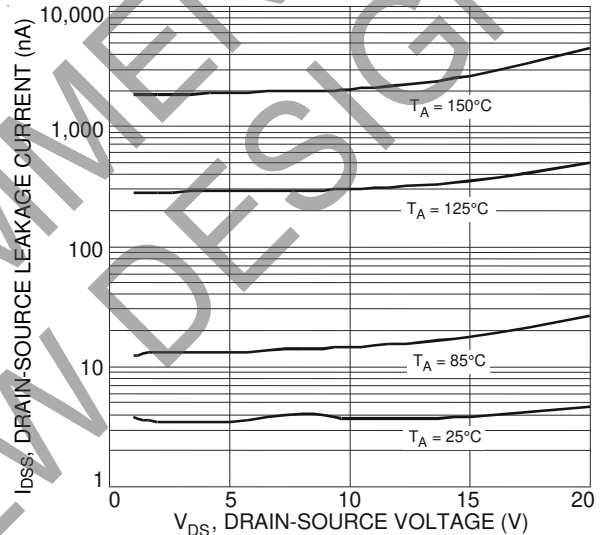


Fig. 10 Typical Drain-Source Leakage Current vs. Drain-Source Voltage

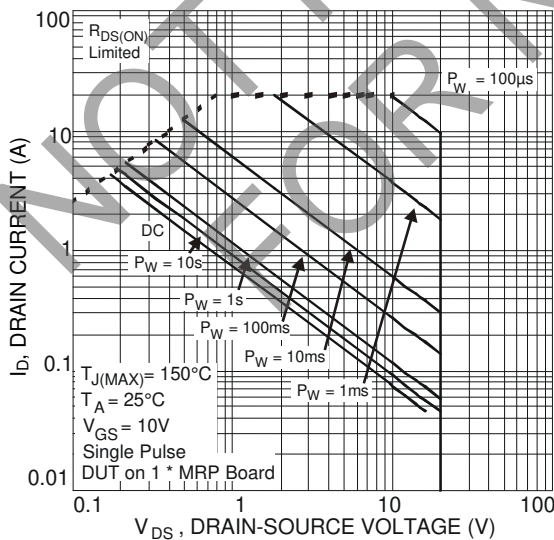


Fig. 11 SOA, Safe Operation Area

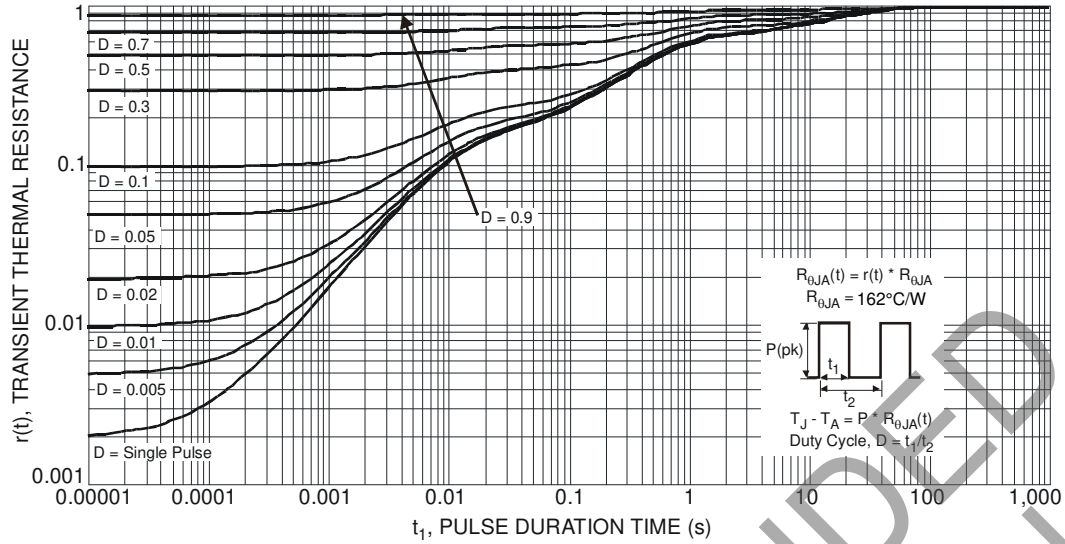
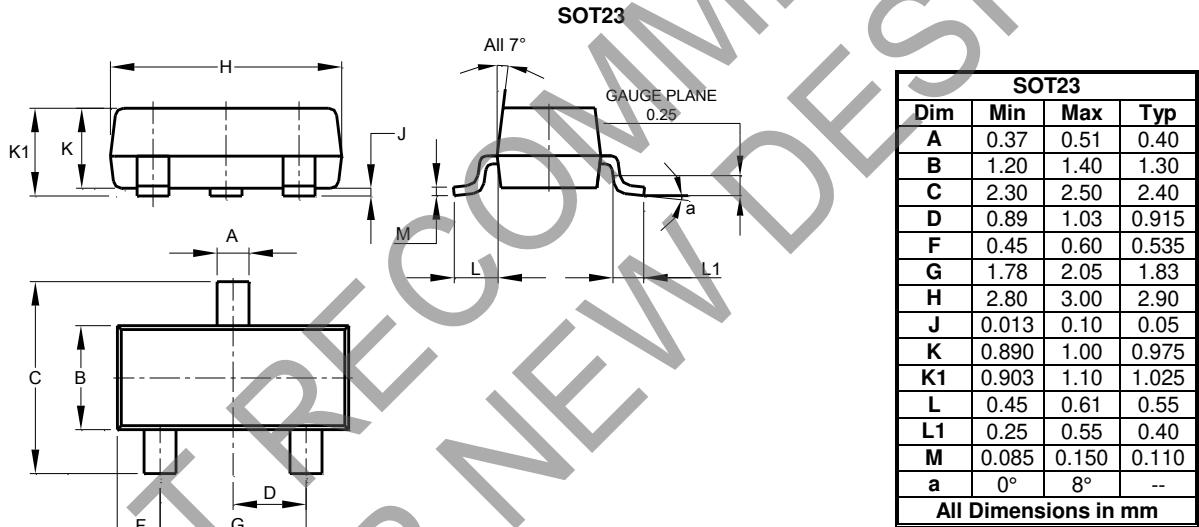


Fig. 12 Transient Thermal Response

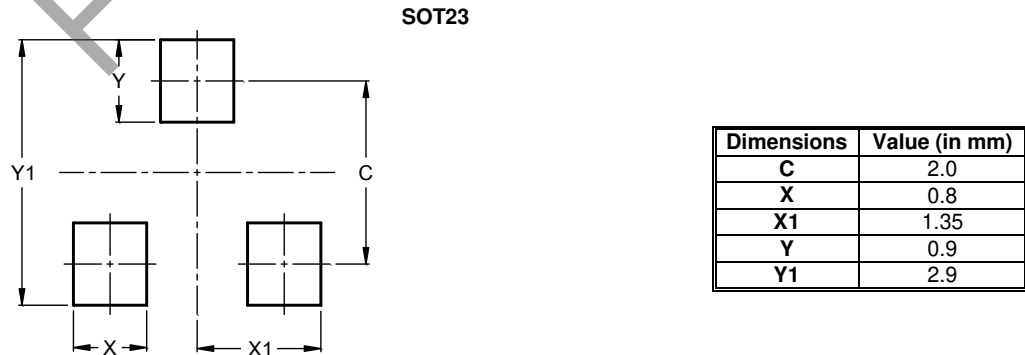
Package Outline Dimensions

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Suggested Pad Layout

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